

SMR 1232 - 31

**XII WORKSHOP ON
STRONGLY CORRELATED ELECTRON SYSTEMS**

17 - 28 July 2000

TRANSPORT MEASUREMENTS ON THE CUPRATES

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These are preliminary lecture notes, intended only for distribution to participants.

(SOME) TRANSPORT PROPERTIES OF CUPRATES ①

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and Department of Physics, University of Cambridge.

PLAN

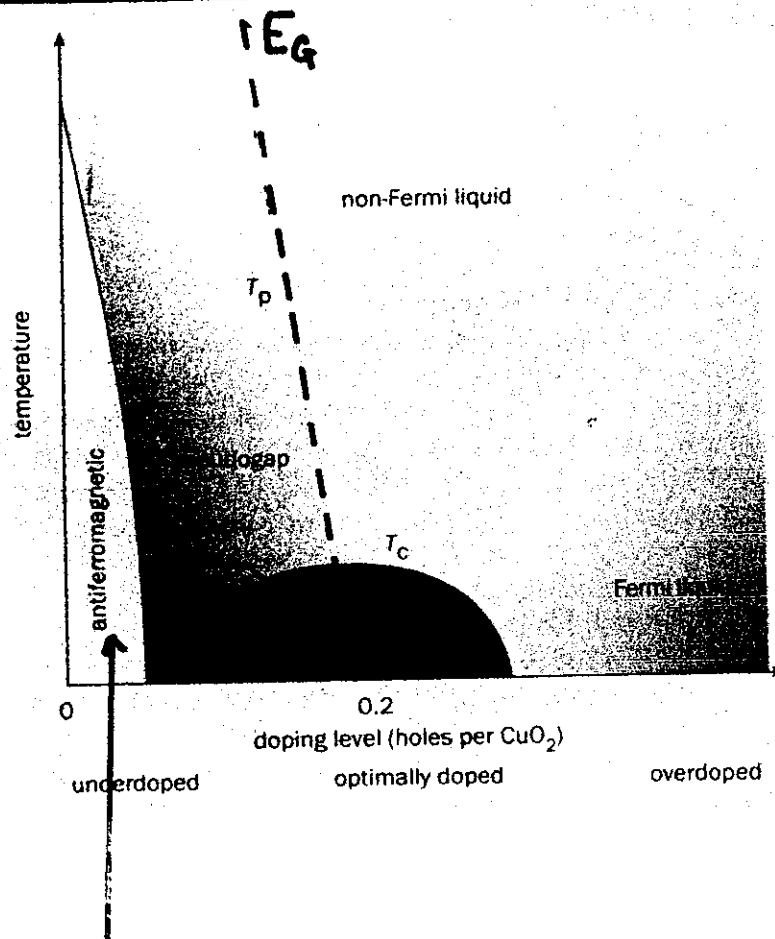
1. REMINDER OF MAIN SPECIFIC HEAT RESULTS AND J. LORAM'S EMPIRICAL MODEL FOR DOS.
2. THERMOELECTRIC POWER - SCALING, STRIPES
3. $\rho(T)$ SCALING Bi:2212, 2201, H. RAFFY'S GROUP (ORSAY) [Tunnelling model c-axis $\rho_c(T, H)$]
4. t - J MODEL CALCULATIONS, PRELOVŠEK ET AL. (HIGH T).
5. POSSIBLE ANALOGIES WITH Kondo EFFECT AND HEAVY FERMIONS
6. SUMMARY AND CONCLUSIONS.
7. A PAIR-BREAKING MODEL FOR THE NON-LINEAR MEISSNER EFFECT.
8. PRELIMINARY CONCLUSIONS. (NLME)

Acknowledgements

- 1-6 D. Babic', A.M. Campbell, N.E. Hussey, W.Y. Liang
K. A. Mirza, J.L. Tallon, J.W. Loram.
- 7-8 A. Parrington, R. Giannetta, W.N. Hardy, J.W. Loram, T.Y.
J.R. Walden

2

1 Cuprate phase diagram mystery



Mott-Hubbard insulator $\text{Cu}^{2+} d^9 S = 1/2$

at what point does standard band theory apply?

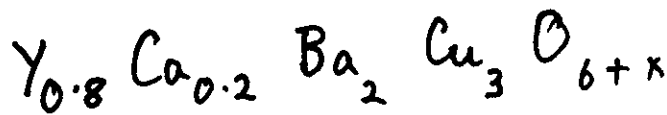
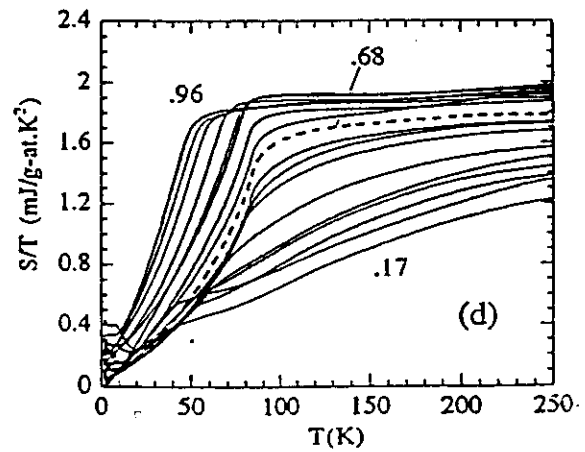
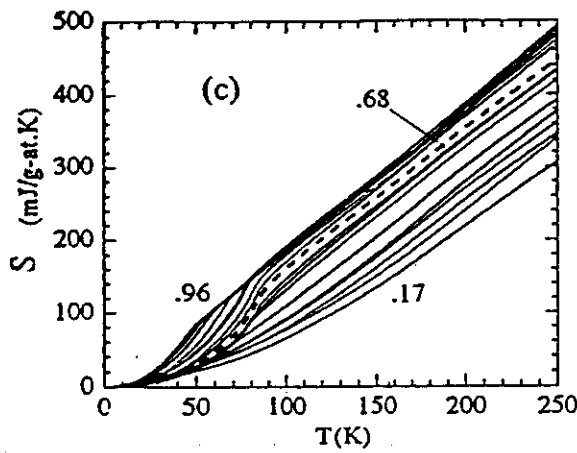
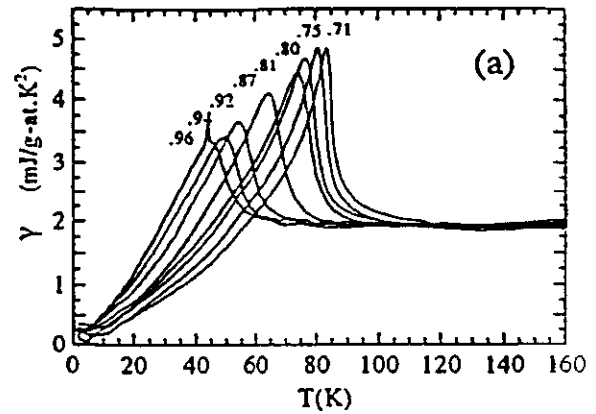
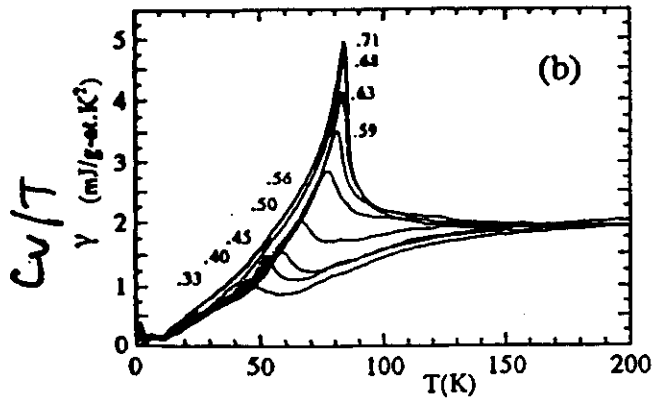
small or large Fermi surface?
 1/4 holes / CuO_2

Batlogg and Varma
 Physics World (2000)

under-doped

overdoped

(3)

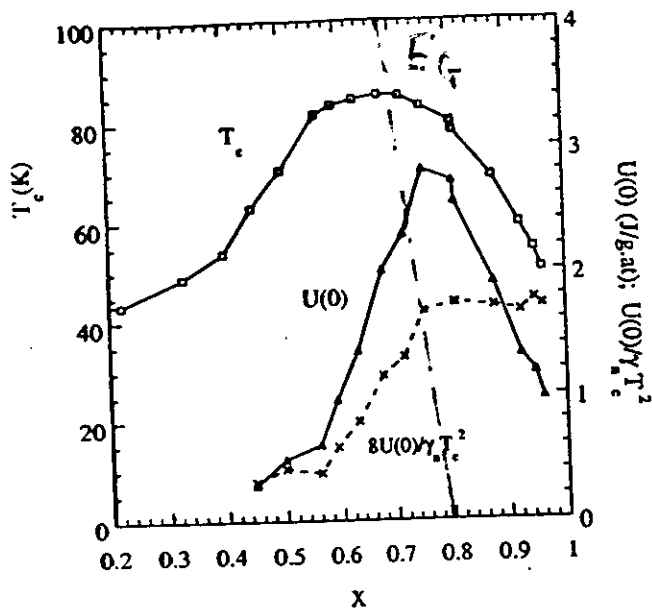


YBCO
Also LSCO
Bi: 2212

J. W. Loram et al

Physica C 282, 1287 (1997)

Representative specific heat results.



J. W. Loram et al
Physica C, 282, 1287
(1997)

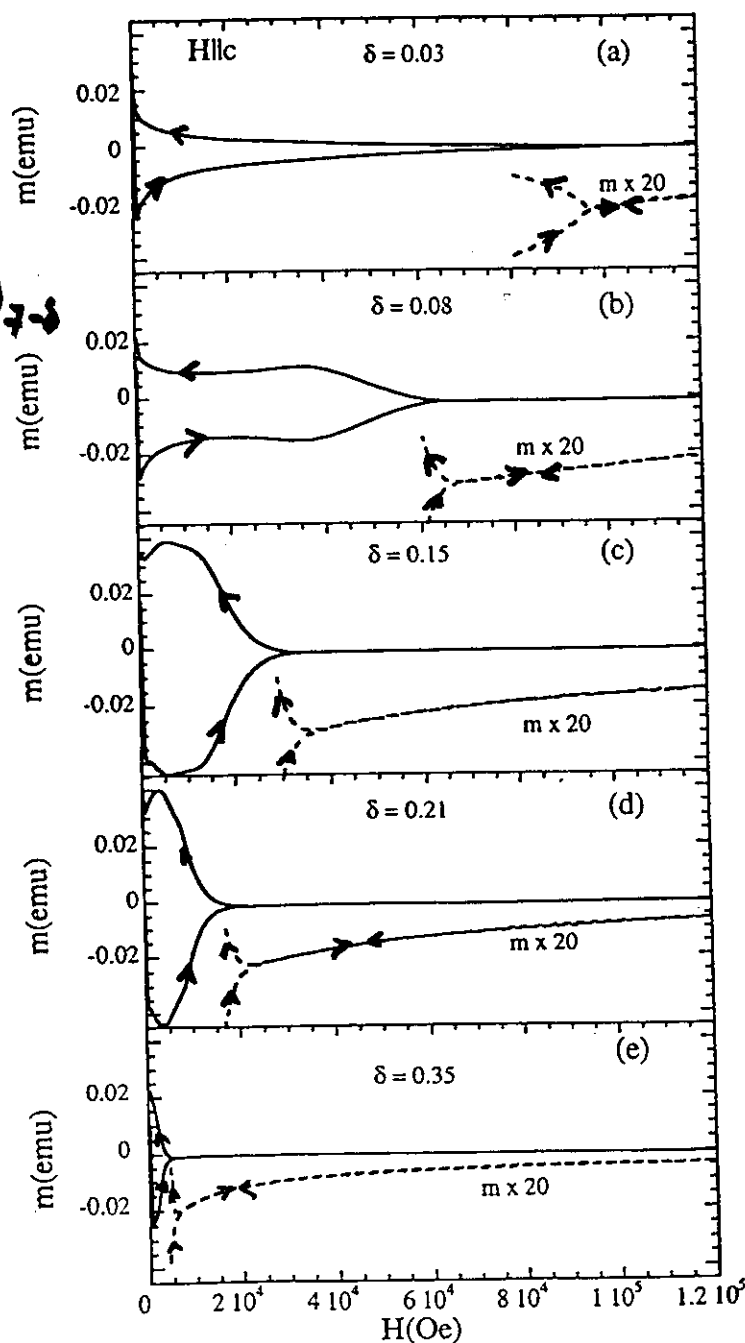
Condensation energy
 $u(0) \equiv M_c(0)^2 / 8\pi$



5mg
 $H \perp CuO_2$
layers

$$\frac{T}{T_c} = 0.8_3$$

D. Babic'
J.R.C. et al
Phys. Rev.
B60, 698
(1999)



Irreversibility
(melting)
Line.

(4)

5

Bi: 2212

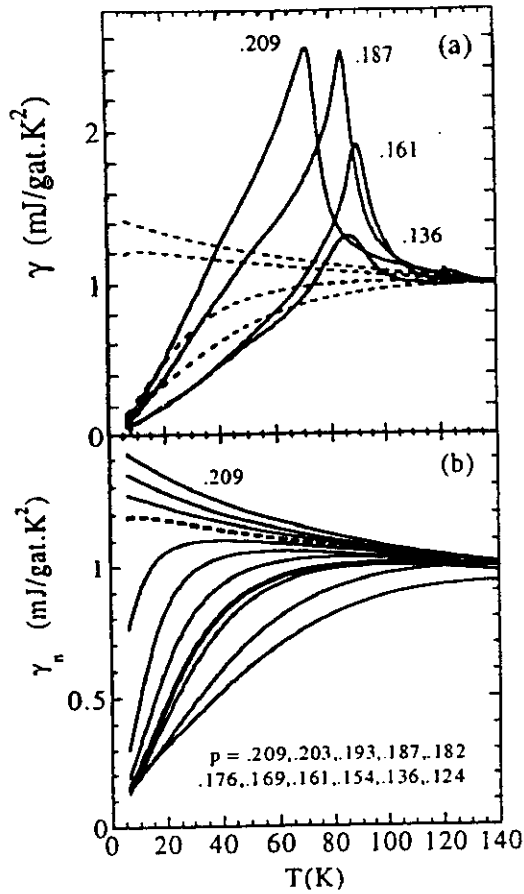


Fig. 6 (a) Broken curves show γ_n below T_c deduced from an extrapolation of S_n from above T_c . A NS pseudogap for $p < p_{\text{crit}} \sim 0.19$ and no pseudogap for $p > p_{\text{crit}}$ follow from the condition $S_n(T_c) = S_s(T_c)$. (b) γ_n for the undoped Bi2212 sample for all p .

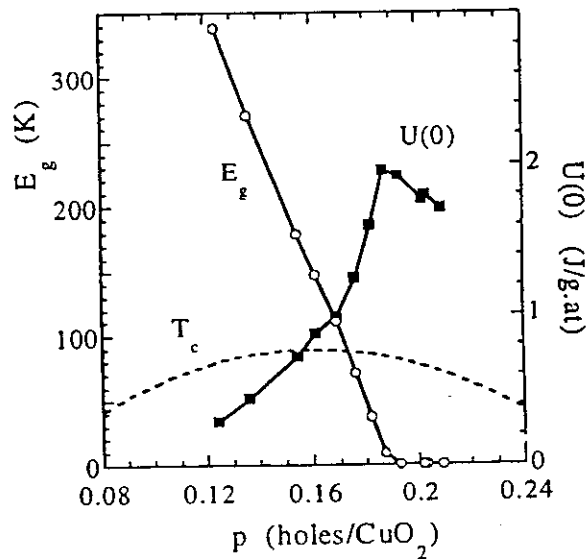


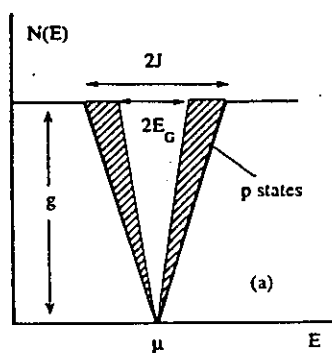
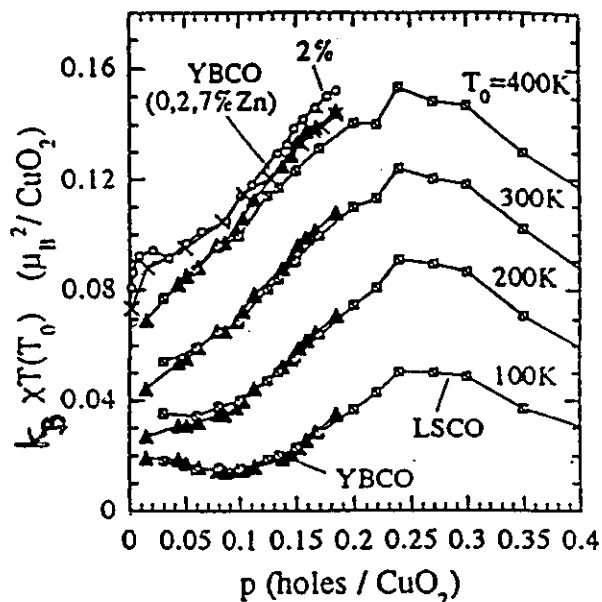
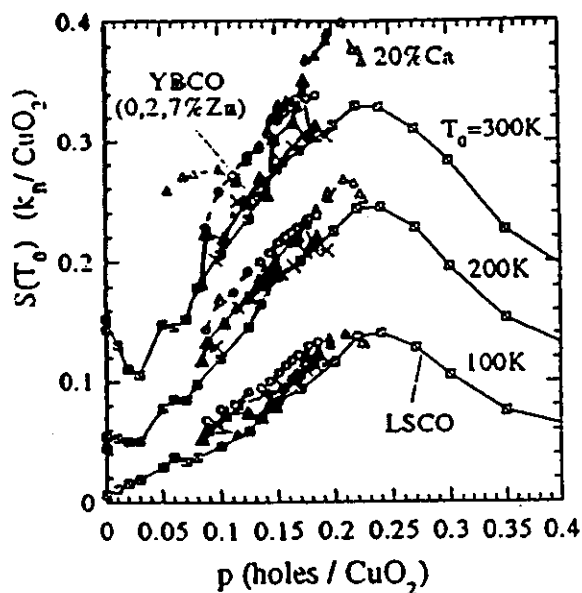
Fig. 5. E_g/k_B , T_c and $U(0)$ for undoped Bi2212.

J.W. Loram
et al.

Procs. Houston conf. Feb. (2000).

$\chi T / S = \text{WILSON RATIO}$

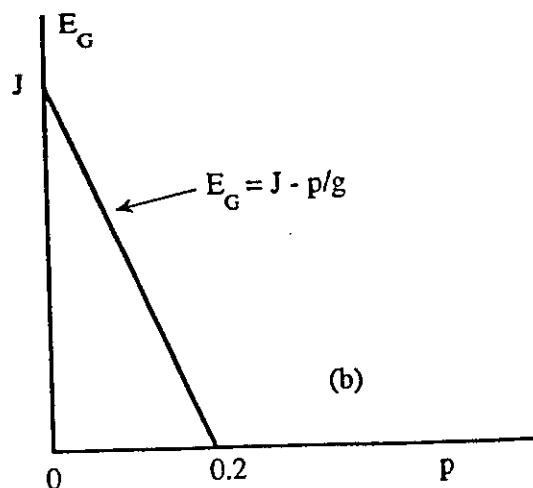
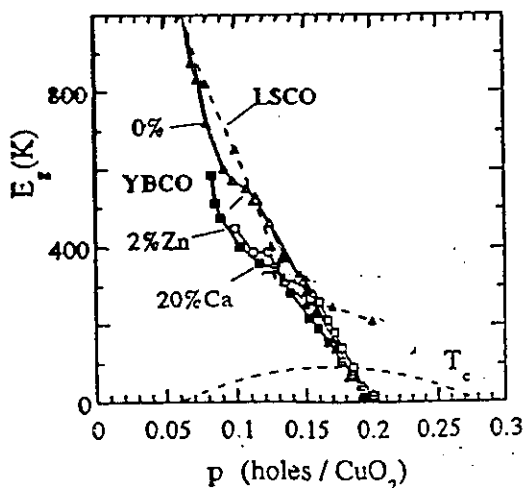
6



t-J type

Empirical description
of correlated state -
Fermion DOS.

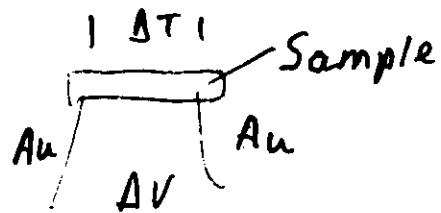
J.W. Loram et al
J. Phys. Chem. Solids
59, 2091 (1998)



Thermoelectric Power

(7)

Easy to measure



$$\left. \frac{\Delta V}{\Delta T} \right|_{\Delta T \rightarrow 0} \equiv \frac{dV}{dT} = S_{\text{sample}} - S_{\text{Au}}$$

for sintered ceramics measure S_{ab} .
TEP insensitive to grain boundaries.

Interpretation

1 el. theory
$$S = \frac{1}{eT} \frac{\int (\epsilon - \mu) \frac{\partial f}{\partial \epsilon} \sigma(\epsilon) d\epsilon}{\int \sigma(\epsilon) \frac{\partial f}{\partial \epsilon} d\epsilon}$$

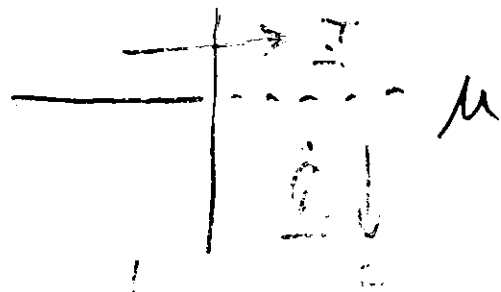
$$\sigma(\epsilon) \propto N(\epsilon) V(\epsilon)^2 \tau(\epsilon)$$

more generally
$$S = \frac{\pi}{T} = \frac{\langle \epsilon - \mu \rangle}{eT}$$

$\langle \epsilon - \mu \rangle$ mean energy / charge carrier
relative to μ

metal
$$S = \frac{k_B}{e} \cdot \frac{T}{\epsilon_F}$$

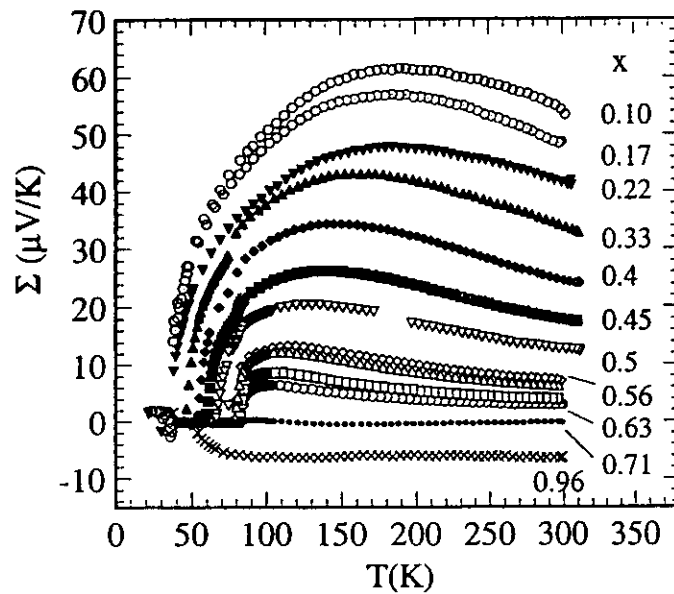
1-10 $\mu\text{V}/\text{K}$ at R.T.



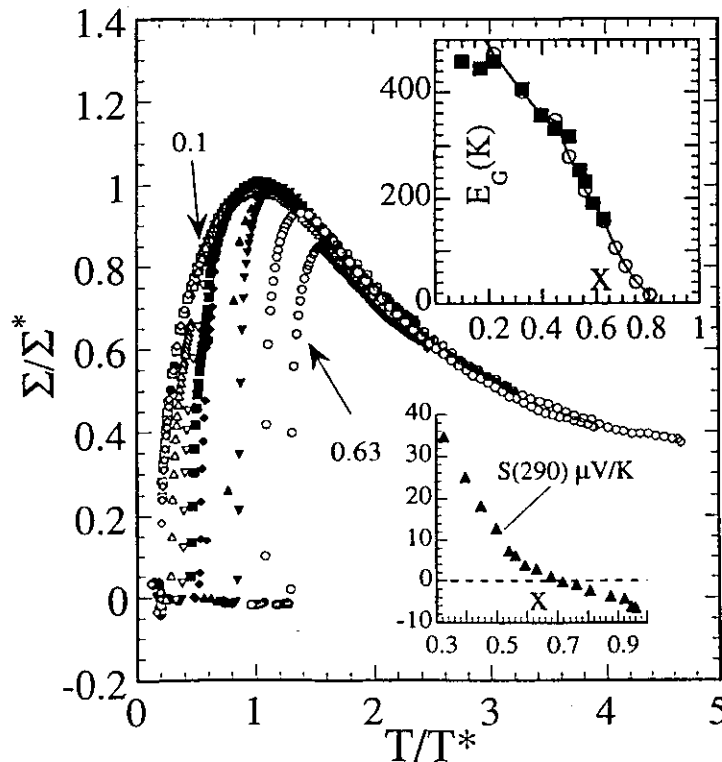
el. TEP very sensitive to higher
order scattering processes.

Thermoelectric power

(8)



J.R.L. and J.W. Loram J. Phys. (France)
+ Proc. Houston conf. (2000) (2000)



■ 2.5 T⁺
○ S(110K)

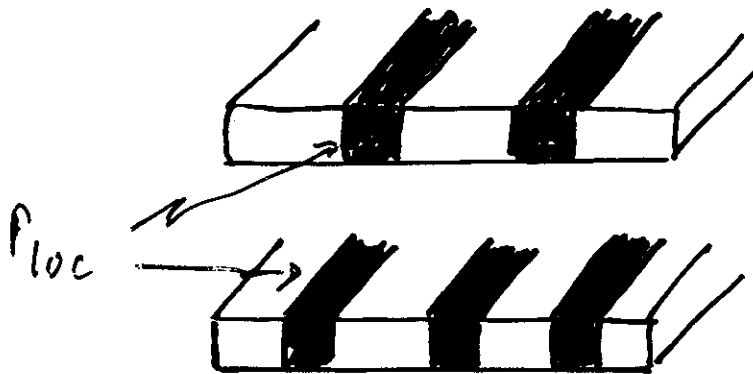
Also
LSCO
YBCO 0.6/2.2
R2212

Also similar scaling in R_H (Batlogg, Uchida)
and $\rho(T)$ {Wuyts et al., Uchida et al.}

Stripes and the TEP

⑨

Several wires in parallel same TEP^{*}



"rivers of charge"

so would not expect TEP to change if P_{loc} stays $\approx$ constant.

(contrast ρ and R_H - both change a lot - depend on P_{av} . ρ/R_H depends on P_{loc})

Random arrangements of static stripes - still valid - TEP of ceramic $\equiv ab$ TEP $\times$ μ

Dynamic stripes - would have to move on time scale of carrier scattering time.

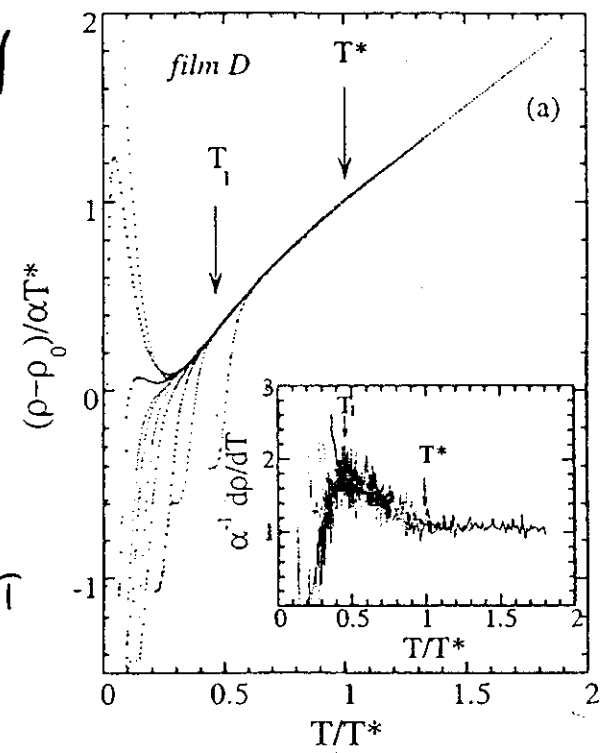
or

^{*} Voltage from non-conducting regions shorted out by conducting ones.

Scaling of resistivity
(ab plane) for:

Bi2212

$$\alpha = \left. \frac{d\rho}{dT} \right|_{T=T^*}$$



H. Raffy et al.

Procs. Houston

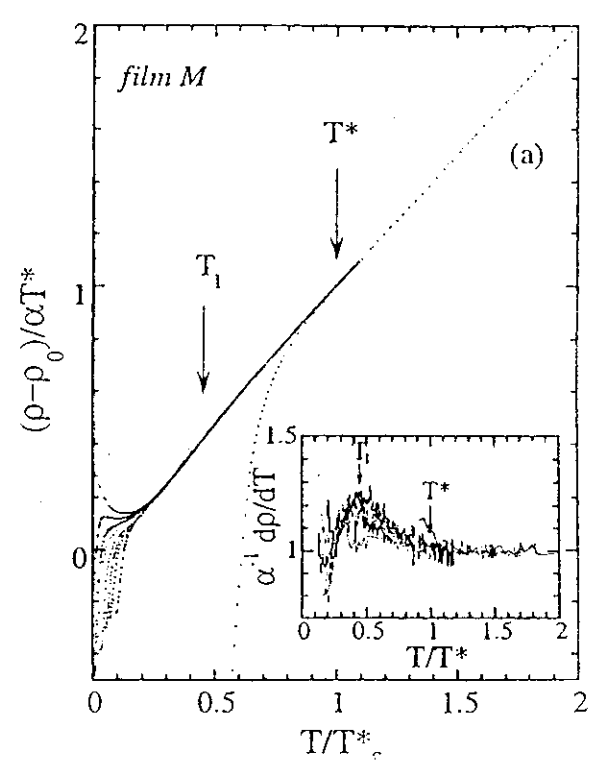
conference (Feb. 2000)

Z. Konstantinovic

Ph.D. Thesis
(Orsay 2000)

Bi(La)2201

$$\frac{\rho - \rho_0}{\alpha T^*} \equiv \frac{\rho(T) - \rho_0}{\rho(T^*) - \rho_0}$$



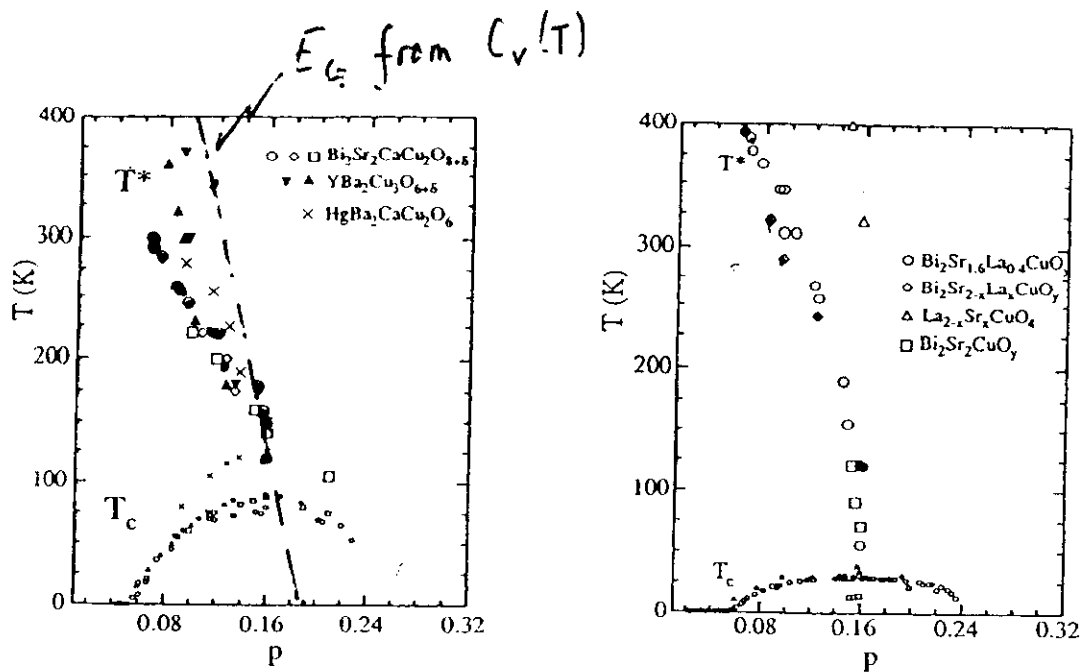


Figure 18 : Comparaison des nos valeurs de T^* (cercles vides) avec les différentes mesures (a) de transport Bi-2212 (diamants vides) [8], (carrés vides) [16], d'YBCO (triangles pointant vers le haut, pleins) [14], (triangles pointant vers le bas, pleins) [13] et (croix) Hg-1212 [24] des systèmes avec deux plans CuO_2 et (b) BiSrLaCuO (diamants) [9] et LSCO (triangles) [25] et Bi-2201 pur (carrés) [3] des systèmes avec un seul plan CuO_2 .

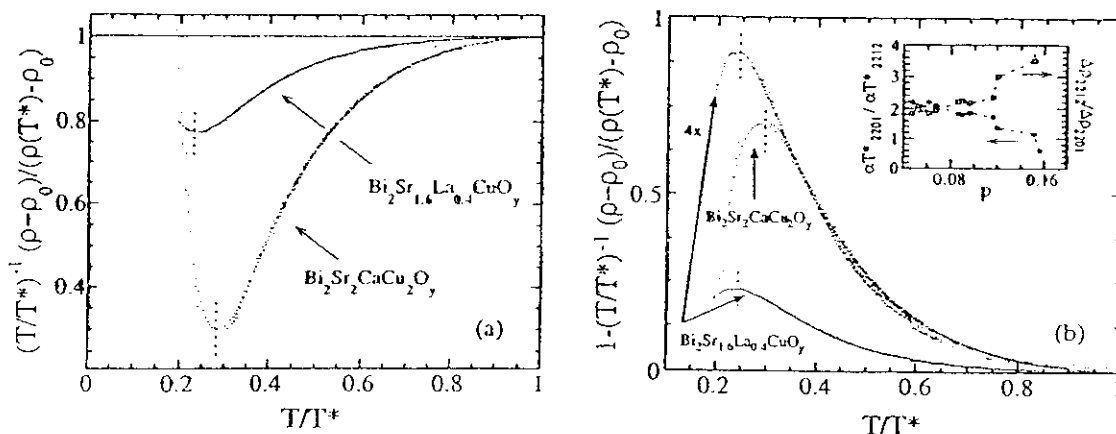
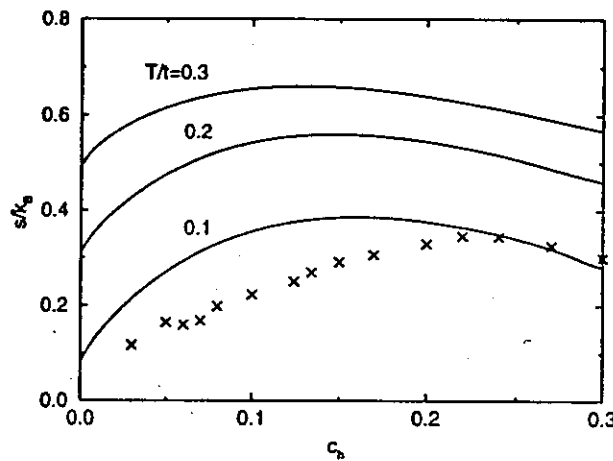


Figure 20 : L'effet de pseudogap sur $\rho(T)$ pour les phases Bi-2212 et Bi(La)-2201. La courbe unique obtenue pour Bi-2212 coïncide avec celle de Bi(La)-2201 après multiplication par un facteur 4 de la quantité A en fonction de la température réduite T/T^* . L'encart montre les rapports $(\alpha T^*)_{2201}/(\alpha T^*)_{2212}$ et $\Delta\rho_{2212}/\Delta\rho_{2201}$ en fonction de p .

Z. Konstantinovic' Ph.D thesis
Orsay (2000)
H. Raffy et al. Houston conf. Feb. 2000

$$H = -t \sum_{\langle ij \rangle s} (\tilde{c}_{j,s}^\dagger \tilde{c}_{i,s} + \text{H.c.}) + J \sum_{\langle ij \rangle} (\tilde{S}_i \cdot \tilde{S}_j - \frac{1}{4} n_i n_j),$$

describing fermions in a tight-binding band with the hopping parameter $t \propto t_{pd}^2/\Delta$. Here $\tilde{S}_i = (1/2) \sum_{s,s'} c_{i,s}^\dagger \vec{\sigma}_{ss'} c_{i,s'}$ are the local spin operators interacting with the exchange parameter $J \propto t_{pd}^4/U_d \Delta < t$. Due to the strong on-site repulsion states with doubly occupied sites are explicitly forbidden and we are dealing with projected fermion operators $\tilde{c}_{i,s} = c_{i,s}(1 - n_{i,-s})$.



doped holes
reduce a.f.
order
release
spin entropy

Figure 4.4: s vs. c_h at several T , calculated in a system with $N = 20$ sites. We show for comparison also experimental results for LSCO by Loram *et al.* (1996) at highest $T = 320 \text{ K} \sim 0.07 t$.

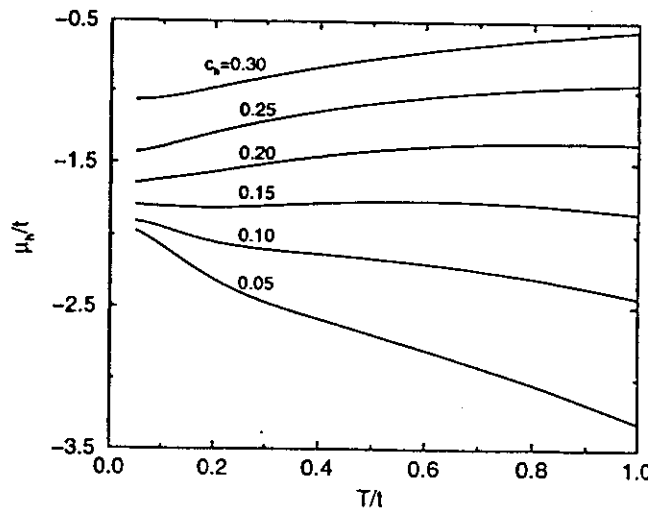


Figure 4.1: Hole chemical potential μ_h vs. T at several dopings c_h .

$$\left. \frac{\partial s}{\partial c_h} \right|_T = - \left. \frac{\partial \mu_h}{\partial T} \right|_{c_h}$$

$$S \sim \frac{1}{e_0 T} [\mu_h(T=0) - \mu_h(T)],$$

(13)

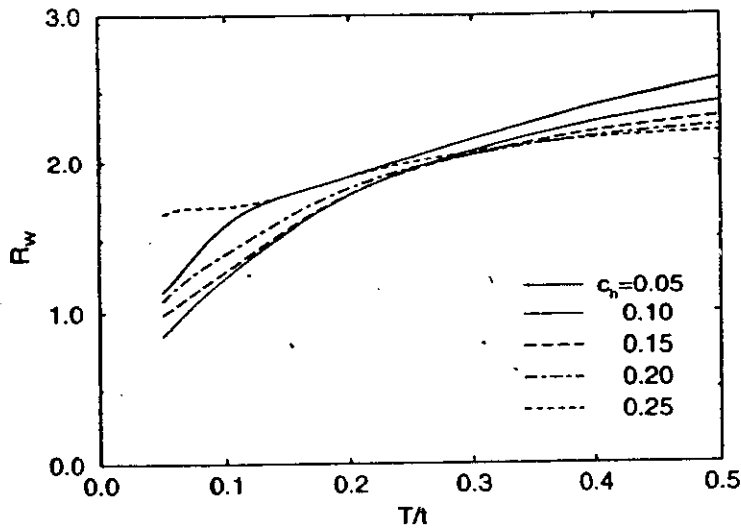


Figure 26. Wilson ratio R_W versus T at several c_h .

$$\rho_0 = \frac{\hbar}{e^2} / \text{layer}$$

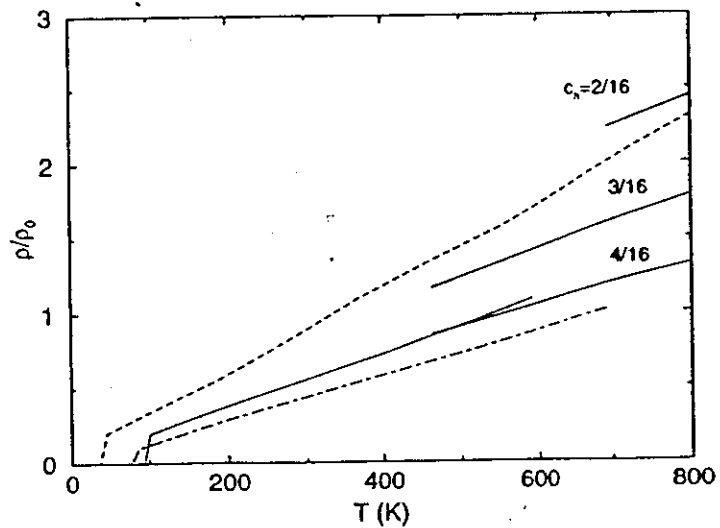


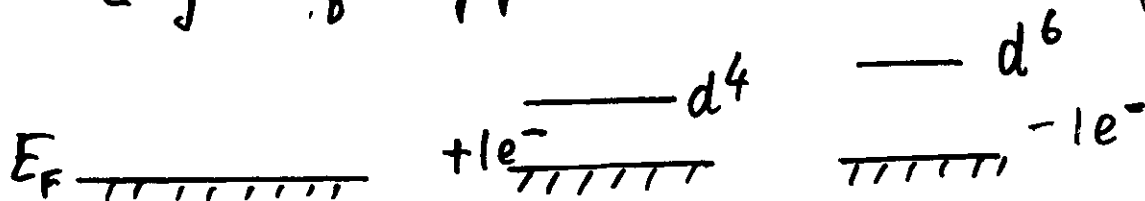
Figure 24. Sheet resistivities $\rho(T)$ for various dopings (full lines) in comparison with measurements in LSCO with $x = 0.15$ (dotted), BSCCO (dashed), and YBCO (dash-dotted).

Jaklic and Prelovšek
numerical studies of t - J model.
Adv. Phys. (2000) 1-85

KONDO EFFECT

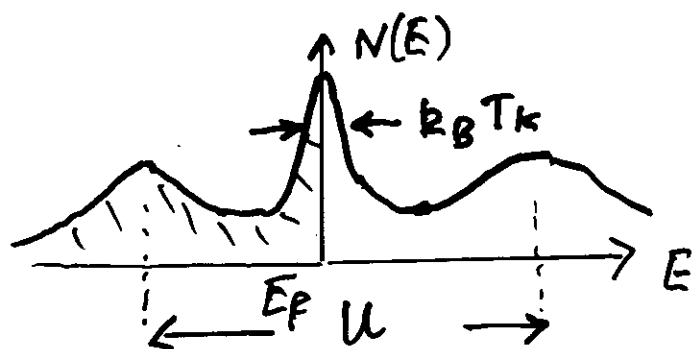
(14)

e.g. few ppm Mn (d^5) in Ag



Mn d^5

RESONANCE AT E_F - SPIN ENTROPY
TRANSFERRED TO CONDUCTION ELECTRONS



$$\Delta C_v \sim \frac{T}{T_K}$$

Mn spin
compensated
by cond. electron

ALSO HAPPENS IN HEAVY FERMION
COMPOUNDS e.g. $CeSn_3$
 Ce^{4+} or Ce^{3+} f^0 or f^1

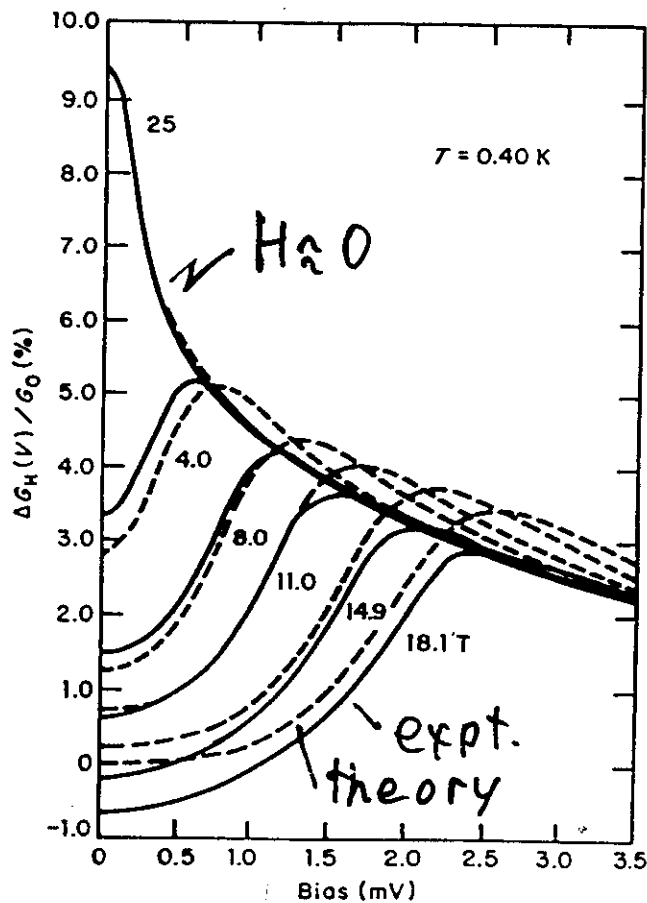
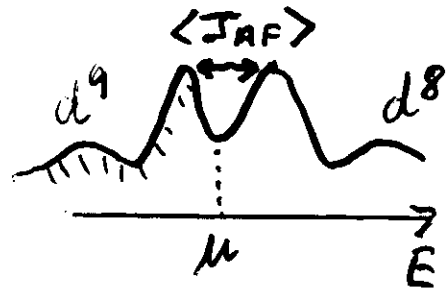
BUT (e.g. LONZARICH GROUP) LDA
BAND STRUCTURE $\rightarrow$ SHAPE OF FERMI
-SURFACE, NOT m^* .

(15)

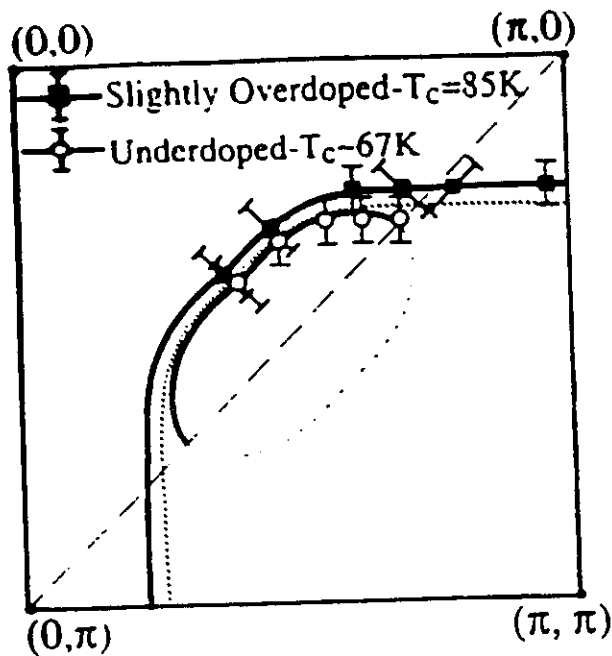
IS THIS A USEFUL WAY OF
LOOKING AT HTS? N.B. T_K LARGE

Cu d^9 spin interacting with
more mobile O $2p$ holes.

MAGNETIC FIELD (OR IN THIS CASE
 J_{AF} - NEAREST NEIGHBOUR EXCHANGE
INTERACTION) "DIGS HOLE" IN RESONANCE
AT E_F . HOLE FILLS AS $\langle J_{AF} \rangle$ IS REDUCED
BY DOPING.

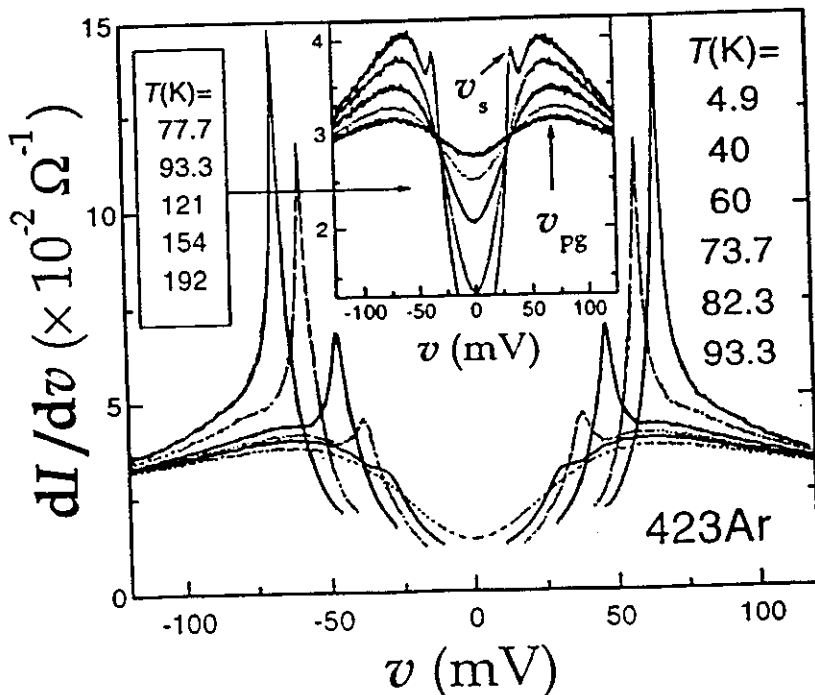
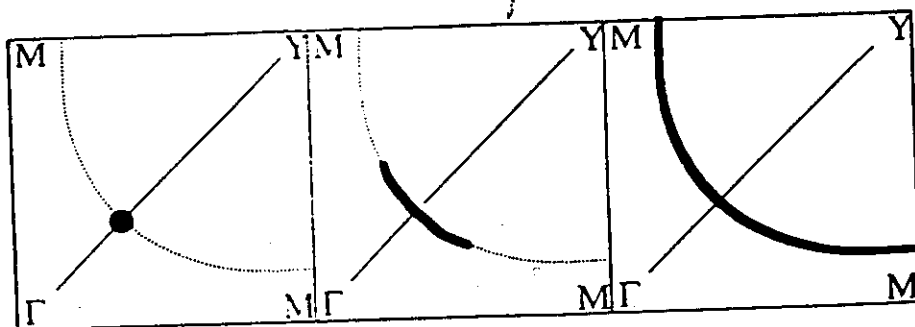


Al|AlO_x|Al
Tunnel
junction
doped
with Fe



From
 T. Timusk and B. Statt
 Repts. Prog. Phys.
 62 1-122 (1999)

Based on recent
 ARPES data
 (Argonne, Stanford...)



c-axis
 Intrinsic
 Tunnelling
 Bi:2212
 Meissner

Krasnov et al (Gothenburg)
 Cond-mat 0002172

Summary and Conclusions

The strange properties of the normal state pseudogap (E_G) suggest a new type of correlated electron system - a quasi-2D doped Mott-Hubbard insulator – not a usual metal or semiconductor.

- For under- and optimal doping, E_G has strong *(weakening)* effect on superconducting properties.
- Unusual transport, but crucially, doping gives 1 state per hole near Fermi energy. $\Delta S/\Delta p \approx k_B$ (above about 100 K) and $\Delta\chi T/\Delta S = 3\mu_B^2/\pi^2 k_B^2$, Wilson ratio for weakly interacting Fermions.
- Variation of E_G (or T^*) and T_c vs. p , like heavy Fermions under pressure – but no evidence for phase transition at T^* .
- Numerical t-J model results agree with data at high T , but no clear picture for E_G . Give “marginal Fermi liquid” results, $\tau^{-1} \sim T^1$, ω^1 . Can this account for empirical $N(E)$?
- Other possibilities for $N(E)$ – holes “dressed” by AF spin waves, 2D equivalent of CH_x (P. Wiegmann), many-body effects e.g. spin fluctuations (Pines et al.), Umklapp el-el processes (Rice et al.)
- many-body resonance with structure near E_F induced by n.n. exchange interactions.

Non-linear Meissner Effect (NLME)

$$\lambda(T, H) - \lambda(T, 0) = \Delta\lambda(H)$$

$$H \leq H_{c1}(T) \quad = \alpha \lambda(T) \frac{|H|}{H_0(T)}$$

$H_0(T) \approx H_c(T)$ Thermodynamic
critical field

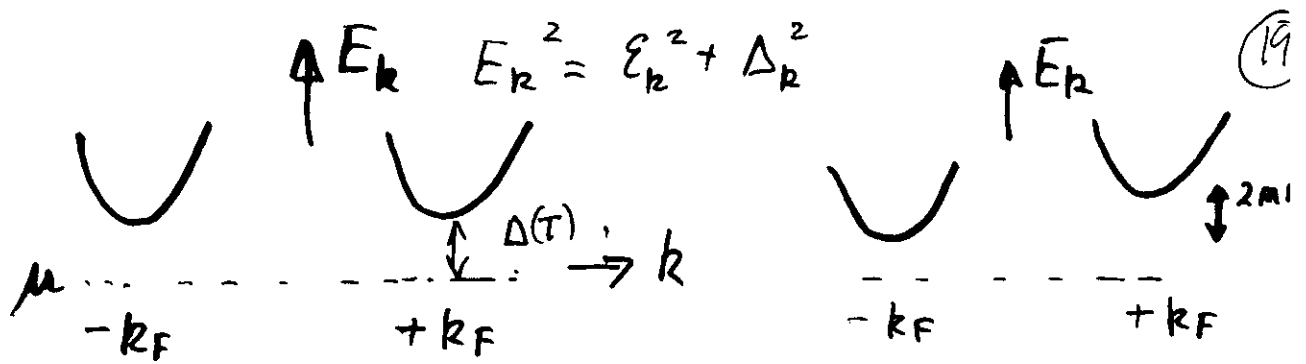
at low T

where Doppler shift $mv_s v_F > k_B T$

Predicted by S.K. Yip and J.A. Sauls
P.R.L. 69 2264 (1992)

Arises from enhanced back-flow
of quasi-particles near the
nodes of "non s-wave" superconductor

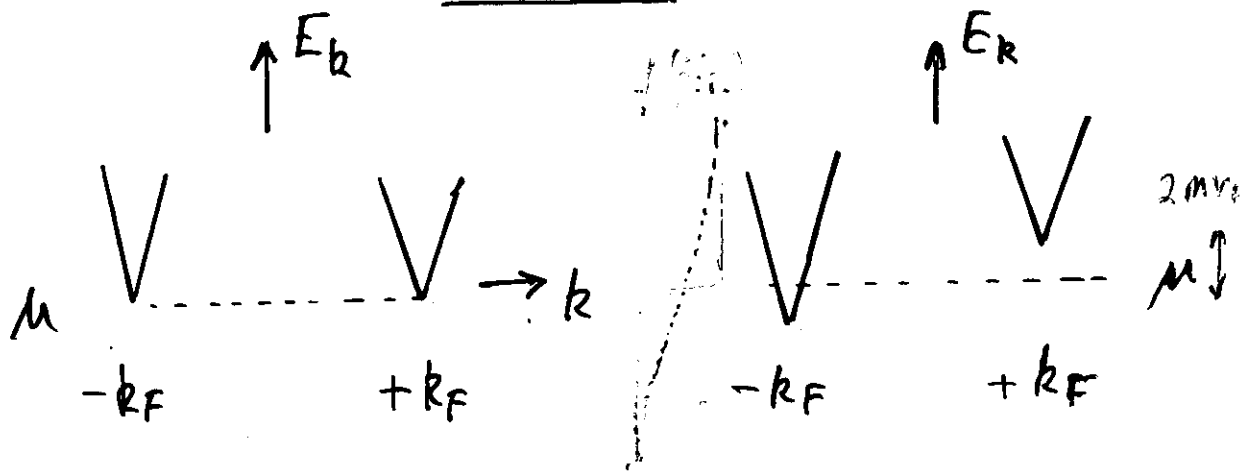
should be good test for nodes
but not really observed experimentally.
expect anisotropy of $\sqrt{2}$ and transverse
moment: also not observed.



$$V_s = 0$$

$$V_s \neq 0$$

s-wave



$$V_s = 0$$

$$V_s \neq 0$$

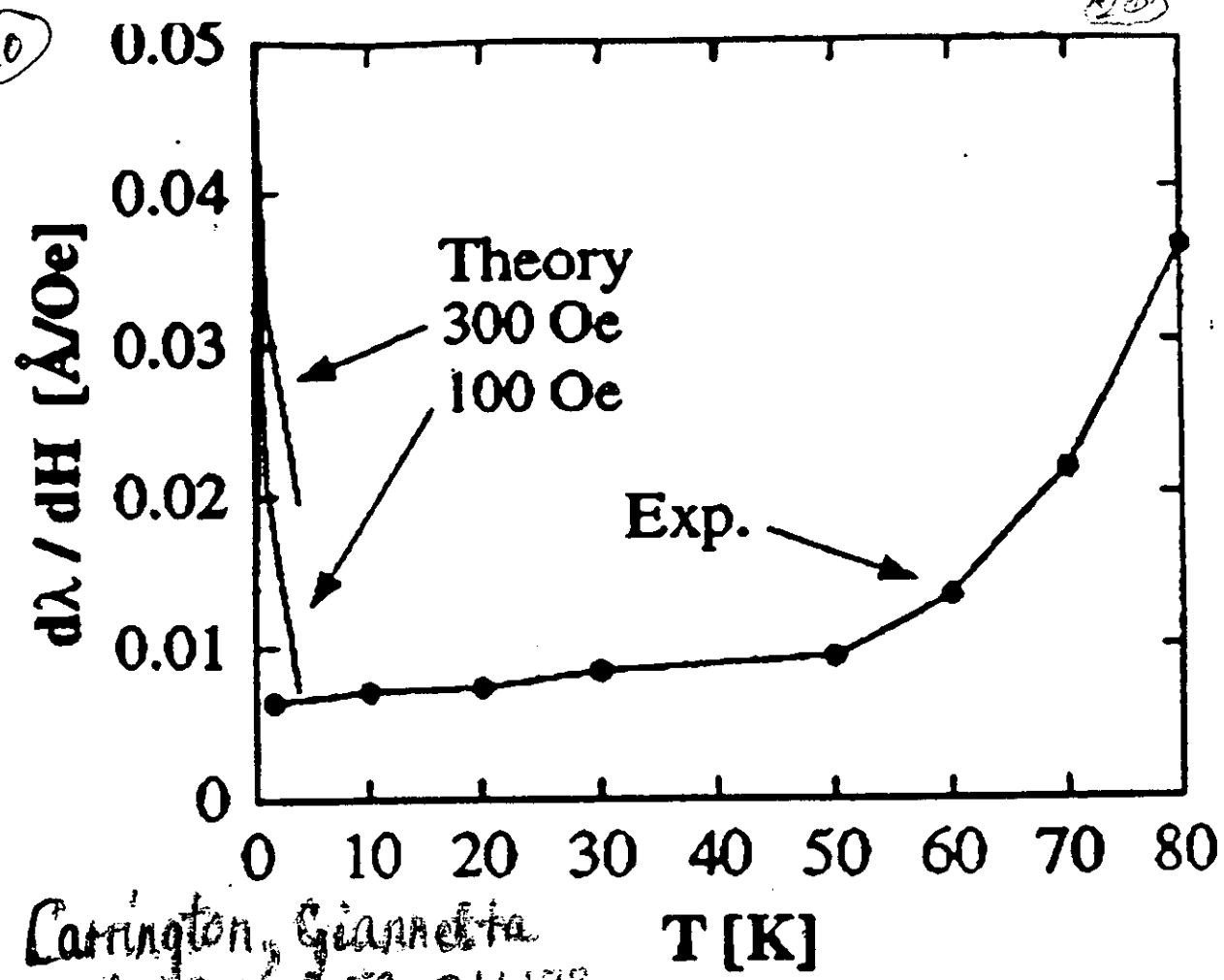
d-wave

when $m v_s v_F \lesssim k_B T$

$$\text{expect } \delta\lambda = \frac{1}{24} \lambda(T) \frac{\Delta(0)}{T} \left(\frac{H}{H_0} \right)^2$$

e.g.

T. Dahm and D.J. Scalapino
Phys. Rev. B 60, 13125
(1999)



Carrington, Giannetta
et al P.R. B59 R14173
(1999)

Bidinosti,
Hardy et al
P.R.L. 83
3277 (1999)

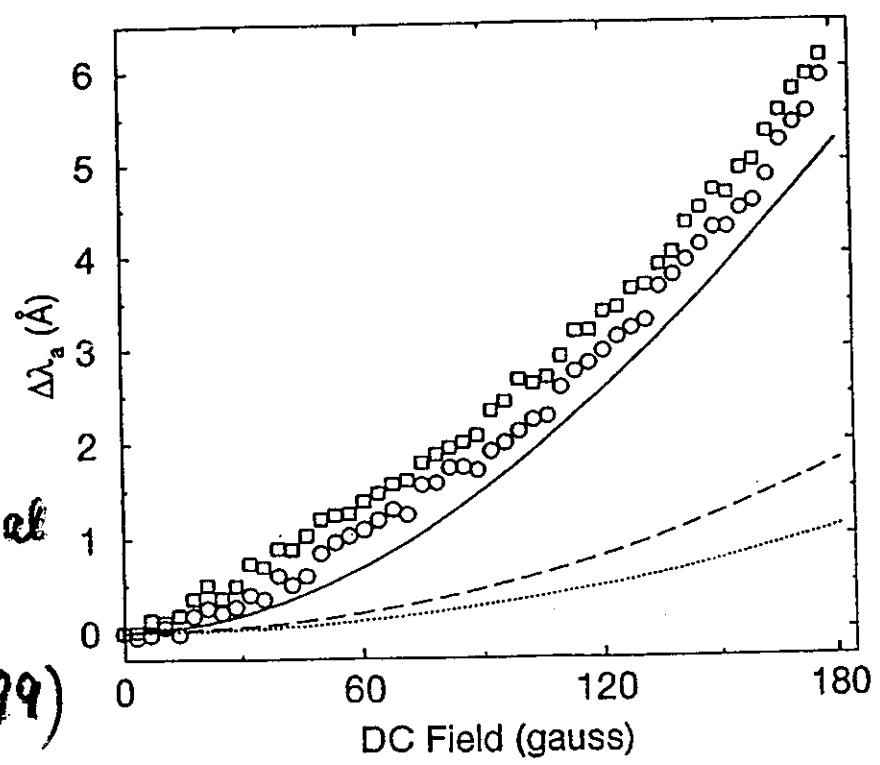


FIG. 4. $\Delta\lambda_a$ as a function of H at various temperatures. Data: 4.2 K (circles), 7.0 K (squares). Theoretical curves: 1.2 K (solid line), 4.2 K (dashed line), 7.0 K (dotted line).

A. Maeda
et al
P.R.L.
74
1202
(1995)

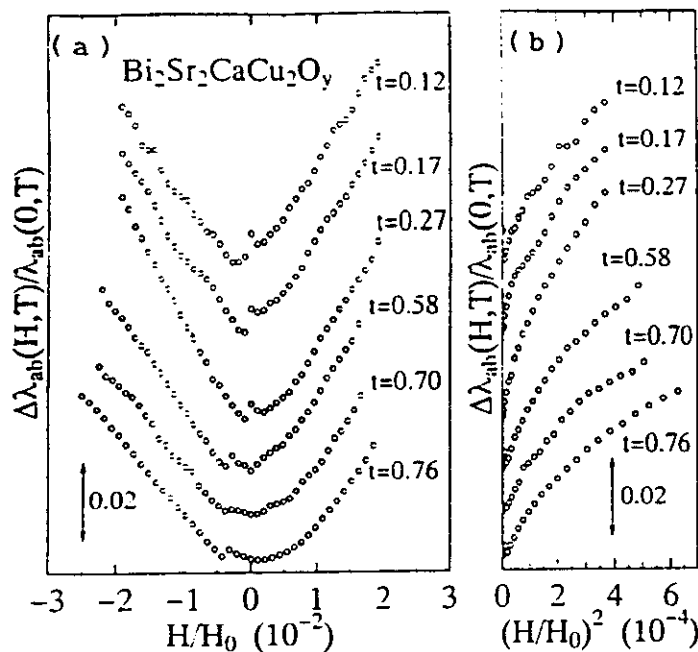


FIG. 2. (a) $\ell \equiv \Delta\lambda_{ab}(H,T)/\lambda_{ab}(0,T)$ as a function of the normalized field $h \equiv H/H_0$ at various temperatures. Temperatures are also normalized to T_c ; $t \equiv T/T_c$. (b) ℓ as a function of h^2 .

Bidinioti,
Hardy et al.
Cond. mat
9808231
YBa_2Cu_3O_{6.95}

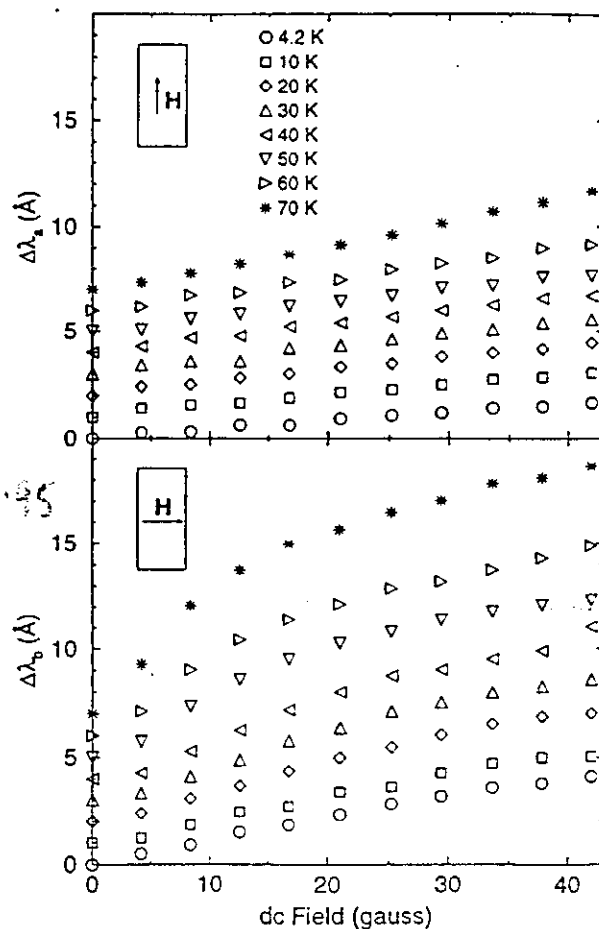
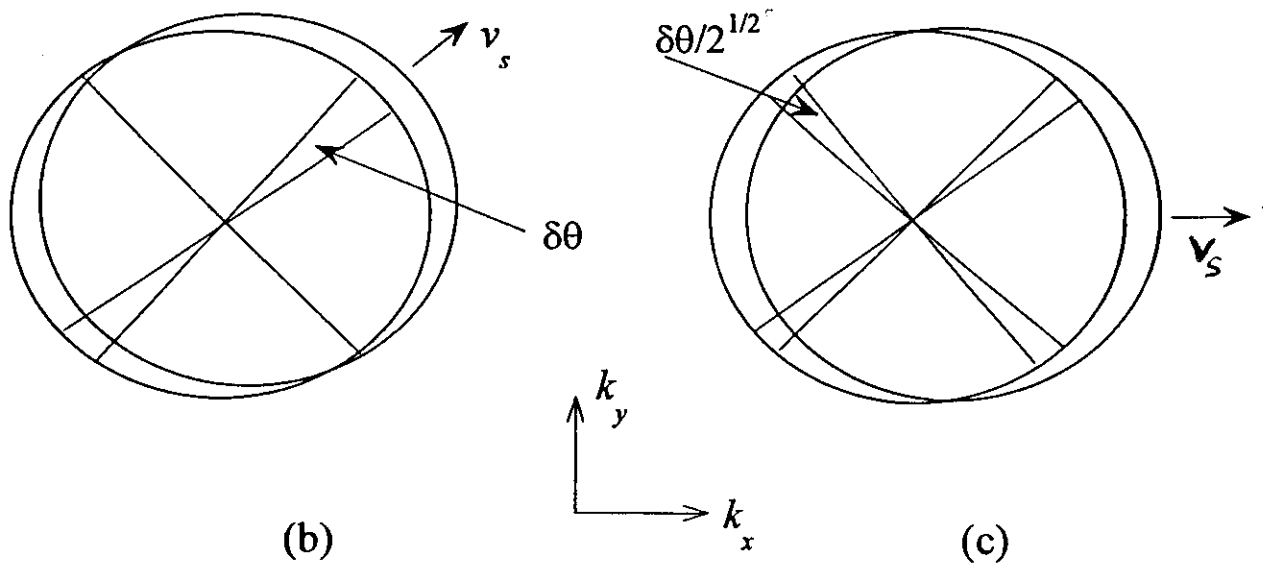
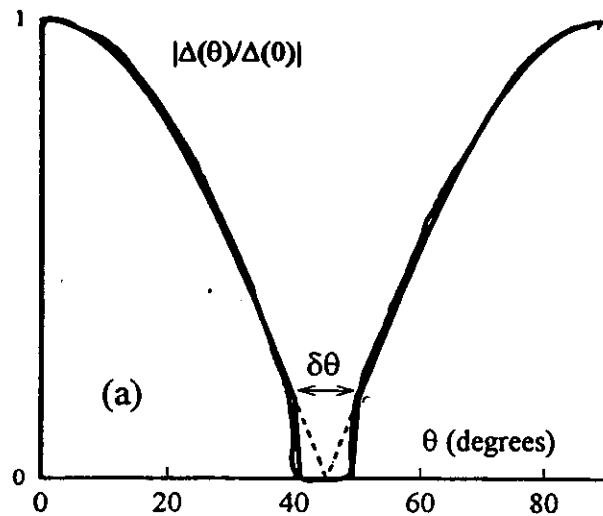


FIG. 3. $\Delta\lambda$ as a function of H for fields parallel (top) and perpendicular (bottom) to the crystal b -axis.

22

$$\Delta(\theta) = \Delta(T) |\cos 2\theta|$$



for the factor:

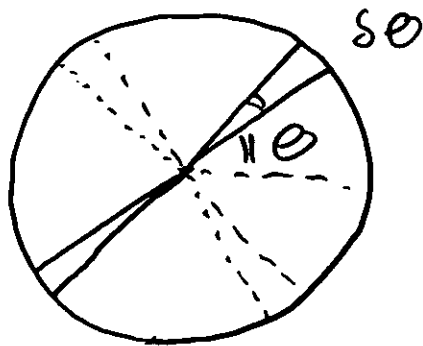
the corresponding phase

$$\Delta(\theta) \leq \Delta(0) \cos 2\theta$$

J.R.C. preprint (June 2000)

Justification

weak coupling d-wave BCS theory



rest frame

$$\underline{v}_s = 0$$

Set $\Delta(T) = 0$ over small angle $\delta\theta$
near nodes

Calculate Free energy using BCS expression find $\Delta F = +\beta(T)(\delta\theta)^3$
($V_{ke} = -V \cos 2\theta_k \cos 2\theta_e$)

But for finite $\underline{v}_s$, K.E. is reduced by $\frac{1}{2} n m v_s^2 \cos^2 \theta \frac{\delta\theta}{\pi}$ per node

minimise F gives:

$$\delta\theta = \frac{m v_F v_s}{\sqrt{2} \Delta(T)} \frac{1}{2.65} \text{ for } \underline{v}_s \parallel \hat{x}, \hat{y}$$

$$\delta\theta = \frac{m v_F v_s}{\Delta(T)} \frac{1}{2.65} \text{ for } \underline{v}_s \parallel \text{nodal dir.}$$

(24)

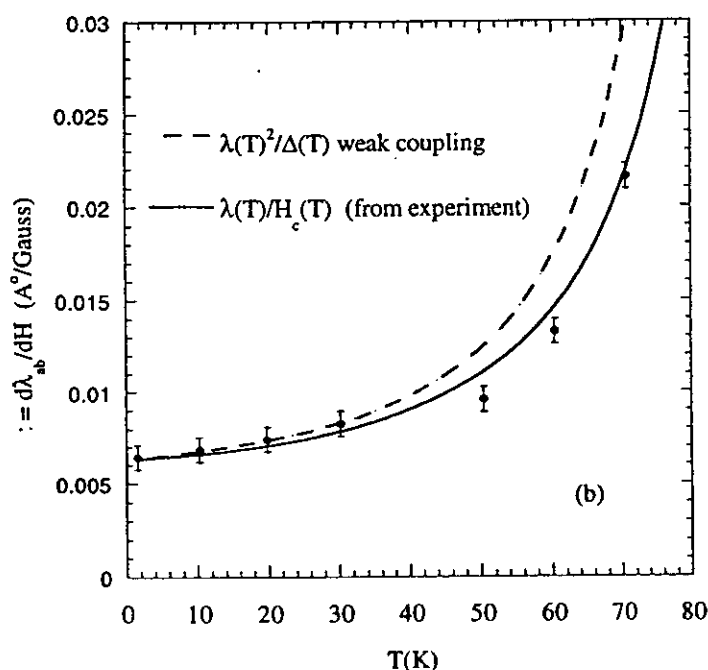
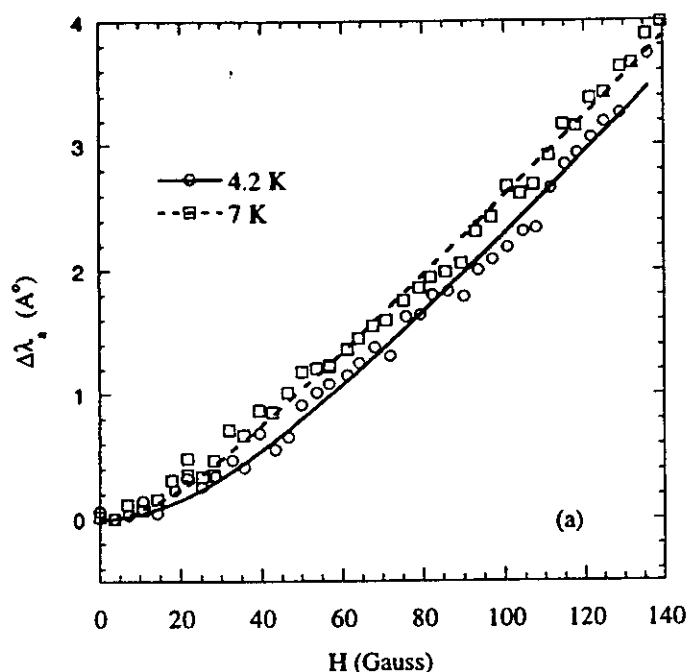
J.R.C.

preprint (2000)

 $\circ \}$ $\text{YBa}_2\text{Cu}_3\text{O}_{6.95}$

data

Bidinosti et al.

 $\text{---} \}$ pair breaking model.

 $\text{YBa}_2\text{Cu}_3\text{O}_{6.95}$

Carrington et al

 $\text{---} \}$ pair-breaking model

effect isotropic

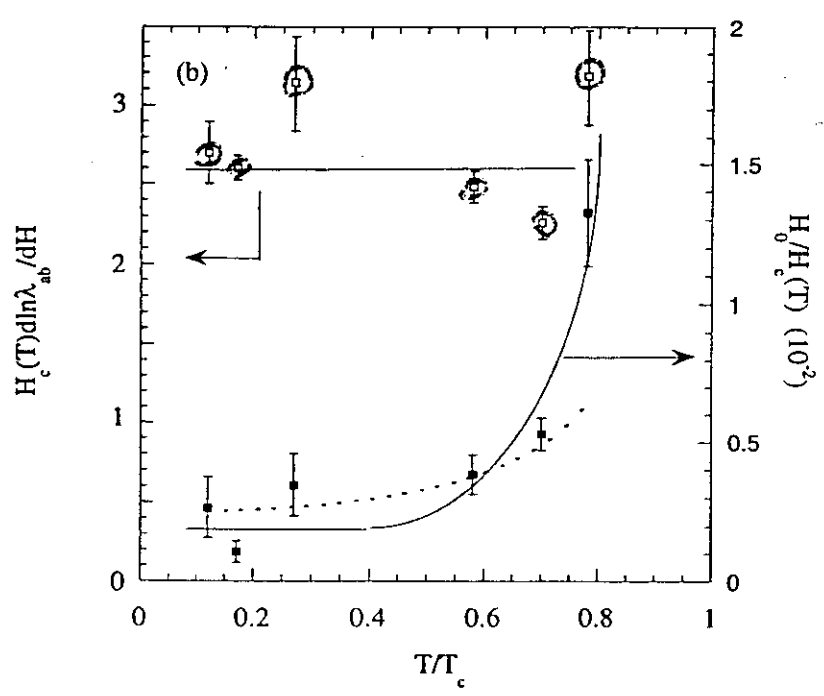
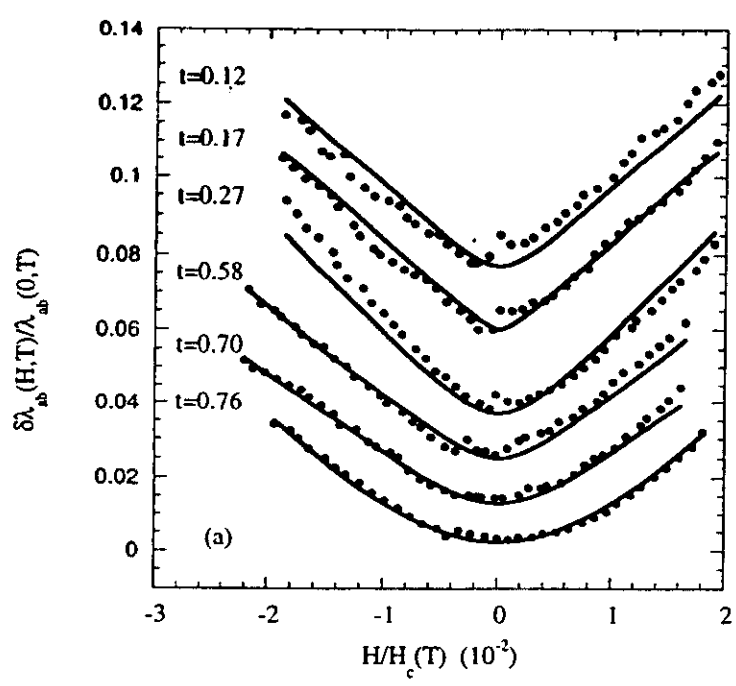
α		
G.L.	0.353	$\frac{\delta\lambda}{\lambda} = \frac{mV_F V_s}{\pi \Delta(T)} = \frac{\alpha H }{H_c(T)}$
BCS _A	0.226	
BCS _B	0.182	$\sigma_T = \frac{\alpha \sqrt{H^2 + H_{00}^2} - H_{00}}{H_c(T)}$

 H_{00} measure of pair breaking in zero field

Bi:2212

• Data of
Maeda et al.

— pair-breaking
model



PRELIMINARY CONCLUSIONS (NLME)

1. PAIR BREAKING MODEL GIVES BETTER DESCRIPTION OF DATA THAN "BACK FLOW" MODEL
2. COULD BE GENERAL PROPERTY OF "NON S-WAVE" SUPERCONDUCTORS
3. HAS SOME THEORETICAL BASIS (FREE ENERGY - BCS ARGUMENT)
4. WOULD GIVE SIMILAR RESULTS TO "BACK FLOW" MODEL IN HIGH FIELDS - SIMILAR NUMBERS OF SIMILAR QUASI-PARTICLES. BUT CONCEPTUALLY DIFFERENT - AND 'BACK-FLOW' EFFECTS SMALLER, (I.E. LESS IMBALANCE BETWEEN +ve and -ve BRANCHES OF E_k vs k CURVES).